

# **Depletion-Mode Power MOSFET**

#### **General Features**

- ESD Improved Capability ≻
- ⊳ Depletion Mode (Normally On)
- ⊳ Proprietary Advanced Planar Technology
- ⊳ Rugged Polysilicon Gate Cell Structure
- ⊳ Fast Switching Speed
- ≻ **RoHS** Compliant
- $\geq$ Halogen-free Available

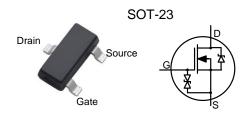
#### **Applications**

- ≻ Suppressing Surge Current
- ≻ Normally-on Switches
- ⊳ Linear Amplifier
- ⊳ High Voltage Regulator
- ⊳ **Constant Current Source**
- ⊳ **Protection Circuits**
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# **Ordering Information**

Part Number	Package	Marking	Remark
DMZ1511E	SOT-23	1511	Halogen Free

<b>BV</b> <sub>DSX</sub>	R <sub>DS(ON)</sub> (Max.)	I <sub>DSS,min</sub>
150V	25 Ω	100mA



Absolute	Maximum Ratings	T <sub>A</sub> =25°C unless otherwise	e specified	
Symbol	Parameter	DMZ1511E	Unit	
V <sub>DSX</sub>	Drain-to-Source Voltage <sup>[1]</sup>	150	V	
V <sub>DGX</sub>	Drain-to-Gate Voltage <sup>[1]</sup>	150	V	
I <sub>D</sub>	Continuous Drain Current	0.1	٨	
I <sub>DM</sub>	Pulsed Drain Current <sup>[2]</sup>	0.4	— A	
P <sub>D</sub>	Power Dissipation	0.50	W	
V <sub>GS</sub>	Gate-to-Source Voltage	±20	V	
$T_L$	Soldering Temperature Distance of 1.6mm from case for 10 seconds	300	°C	
$T_{J}$ and $T_{STG}$	Operating and Storage Temperature Range	-55 to 150		

Caution: Stresses greater than those listed in the "Absolute Maximum Ratings" may cause permanent damage to the device.

#### **Thermal Characteristics**

Symbol	Parameter	DMZ1511E	Unit
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	250	K/W

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# **Electrical Characteristics**

#### **OFF** Characteristics

OFF Characteristics					$T_A = 25^{\circ}C$ unless otherwise specified	
Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions
BV <sub>DSX</sub>	Drain-to-Source Breakdown Voltage	150			V	$V_{GS}$ =-5V, $I_D$ =250 µA
	Drain-to-Source Leakage Current			10	μΑ	$V_{DS}$ =150V, $V_{GS}$ =-5V
$I_{D(OFF)}$				1.0	mA	V <sub>DS</sub> =150V, V <sub>GS</sub> =-5V T <sub>J</sub> =125°C
I <sub>GSS</sub>	Gate-to-Source Leakage Current			20	μA	$V_{GS}$ =+20V, $V_{DS}$ =0V
				20		$V_{GS}$ =-20V, $V_{DS}$ =0V

#### **ON Characteristics**

 $T_A = 25^{\circ}C$  unless otherwise specified

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions
I <sub>DSS</sub>	Saturated Drain-to-Source Current	100			mA	$V_{GS}=0V, V_{DS}=25V$
R <sub>DS(ON)</sub>	Static Drain-to-Source On-Resistance			25	Ω	$V_{GS}=0V$ , $I_D=50mA^{[3]}$
V <sub>GS(OFF)</sub>	Gate-to-Source Cut-off Voltage	-3.3		-1.5	V	$V_{DS}=3V, I_{D}=8\mu A$
gfs	Forward Transconductance		0.24		S	V <sub>DS</sub> =10V, I <sub>D</sub> =50mA

Dynamic Characteristics			Essentially independent of operating temperature			
Symbol	Parameter	Min.	Тур.	Max.	Unit	<b>Test Conditions</b>
C <sub>ISS</sub>	Input Capacitance		12.8		pF	V <sub>GS</sub> =-10V
C <sub>OSS</sub>	Oput Capacitance		5.4			$V_{\rm DS}=25V$ f=1.0MHz
C <sub>RSS</sub>	Reverse Transfer Capacitance		3.3			
Q <sub>G</sub>	Total Gate Charge		3			
Q <sub>GS</sub>	Gate-to-Source Charge		0.23		nC	V <sub>GS</sub> =-10V~0V V <sub>DS</sub> =75V, I <sub>D</sub> =100mA
Q <sub>GD</sub>	Gate-to-Drain (Miller) Charge		1.1			

**Resistive Switching Characteristics** 

Essentially independent of operating temperature

Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions
t <sub>d(ON)</sub>	Turn-on Delay Time		7		ns	$V_{GS}=-10V \sim 0V$ $V_{DD}=75V, I_{D}=100mA$ $R_{G}=20 \ \Omega$
t <sub>rise</sub>	Rise Time		16			
t <sub>d(OFF)</sub>	Turn-off Delay Time		25			
t <sub>fall</sub>	Fall Time		120			

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Source-Drain Diode Characteristics					T <sub>A</sub> =25°C unless otherwise specified		
Symbol	Parameter	Min	Тур.	Max.	Units	<b>Test Conditions</b>	
V <sub>SD</sub>	Diode Forward Voltage			1.2	V	I <sub>SD</sub> =100mA, V <sub>GS</sub> =-5V	
		•			•		

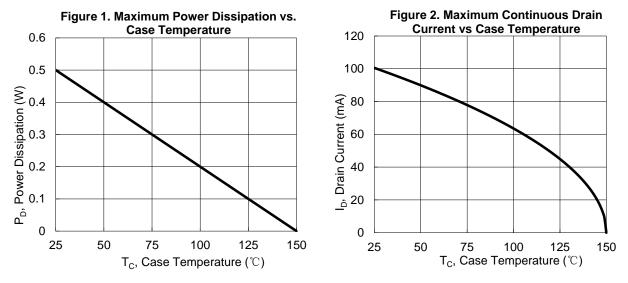
NOTE:

[1]  $T_J$ =+25°C to +150°C

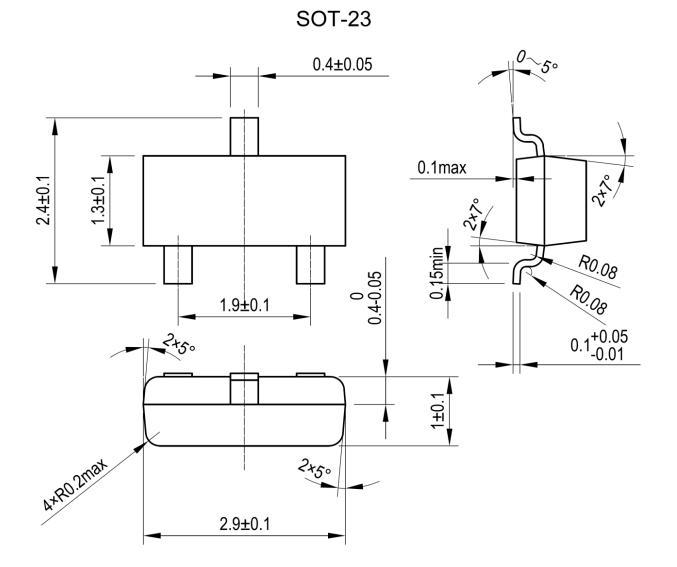
[2] Repetitive rating, pulse width limited by maximum junction temperature. [3] Pulse width $\leq$ 380 µs; duty cycle $\leq$ 2%.

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# **Typical Characteristics**









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